

# GH5C105B3A

## Compact Hologram Laser for Automotive CD-ROM Drive

### ■ Features

- (1) Wide operating temperature for use in automotive equipment
- (2) With built-in OPIC<sup>®</sup> (response speed : MIN. 3MHz)  
(Both for CD car navigation systems and CD players)
- (3) Super-thin (4.8mm thickness) and compact package enables thin and compact pick-up design.
- (4) With built-in beam splitter and diffraction grating

<sup>®</sup>OPIC : (Optical IC) is a trademark of SHARP Corporation.

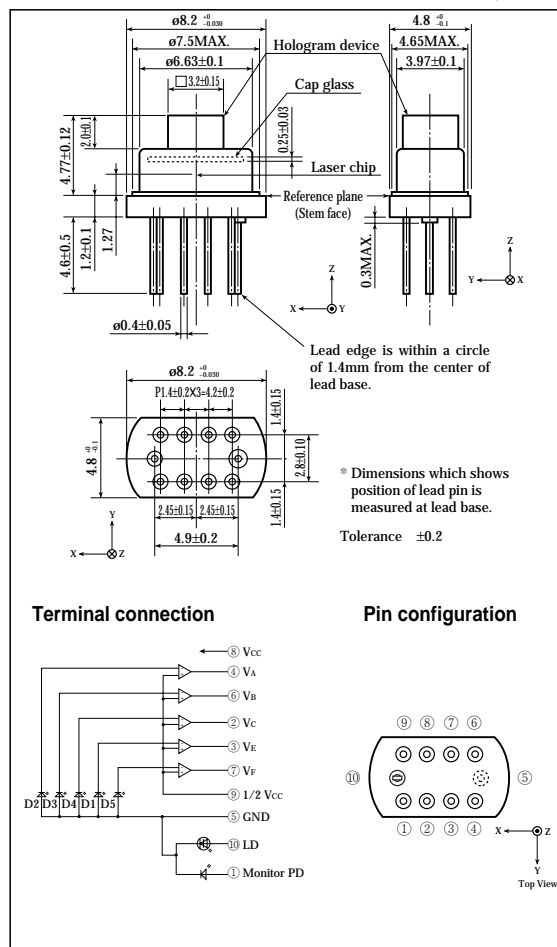
An OPIC consists of a light-detecting element and a signal-processing circuit integrated onto a single chip.

### ■ Applications

- (1) CD players for automotive use
- (2) CD car navigation systems

### ■ Outline Dimensions

(Unit : mm)



### ■ Absolute Maximum Ratings

(T<sub>C</sub>=25°C)

Parameter	Symbol	Rating	Unit
*1 Optical power output	P <sub>H</sub>	4.3	mW
Reverse voltage	V <sub>R</sub>	2	V
		30	V
OPIC supply voltage	V <sub>CC</sub>	6	V
*2 Operating temperature	T <sub>opr</sub>	-10 to +80	°C
*2 Storage temperature	T <sub>stg</sub>	-40 to +85	°C
*3 Soldering temperature	T <sub>sold</sub>	260	°C

\*1 Output power from hologram laser, CW (Continuous Wave) drive

\*2 Case temperature

\*3 At the position of 1.6mm from the lead base (Within 5s)

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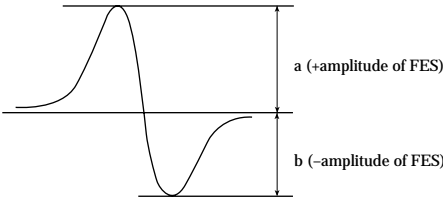
Electro-optical Characteristics

(Vcc=5V, Tc=25°C)

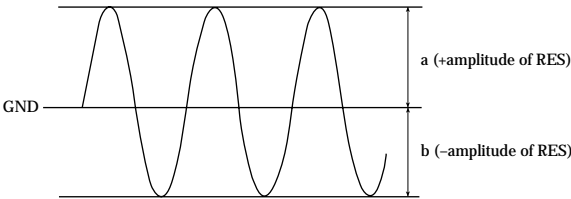
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
① Focal offset	DEF	V <sub>RF</sub> =1.1V	-0.7	-	+0.7	μm
② Focal error symmetry	B <sub>FES</sub>	V <sub>RF</sub> =1.1V	-25	-	+25	%
③ Radial error balance	B <sub>RES</sub>	P <sub>H</sub> =3.0mW	-25	-	+25	%
④ RF output amplitude	V <sub>RF</sub>	P <sub>H</sub> =3.0mW	0.90	(1.70)	2.80	V
⑤ FES output amplitude	V <sub>FES</sub>	V <sub>RF</sub> =1.1V	0.46	(0.70)	0.94	V
⑥ RES output amplitude	V <sub>RES</sub>	V <sub>RF</sub> =1.1V	0.16	(0.23)	0.31	V
Threshold current	I <sub>th</sub>	—	-	(25)	39	mA
Operating current	I <sub>op</sub>	P <sub>H</sub> =2.7mW	-	(36)	50	mA
Operating voltage	V <sub>op</sub>	P <sub>H</sub> =2.7mW	-	(1.75)	2.5	V
Wavelength	λ <sub>p</sub>	P <sub>H</sub> =2.7mW	770	(780)	795	nm
Output current	I <sub>m</sub>	P <sub>H</sub> =2.7mW, V <sub>R</sub> =15V	(0.12)	(0.55)	1.00	mA
Differential efficiency	η <sub>d</sub>	$\frac{1.8\text{mW}}{I(2.7\text{mW})-I(0.9\text{mW})}$	0.17	(0.27)	0.55	mW/mA

① Distance between FES=0 and jitter minimum point  
At the condition of FES sensitivity = 20%/1μm

② (a-b) / (a+b)



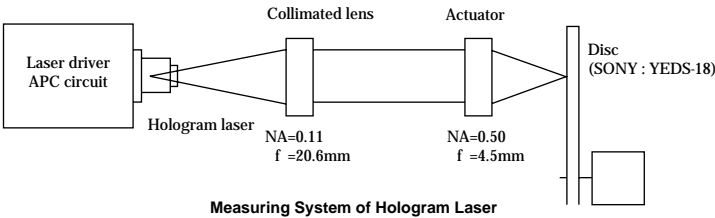
③  $\frac{a-b}{2 \times (a+b)}$  Offset of hologram laser is included.



④ Amplitude of V<sub>A</sub>+V<sub>B</sub>+2V<sub>C</sub> (focal servo ON, radial servo ON)

⑤ V<sub>A</sub>-V<sub>B</sub> (Focal vibration)

⑥ V<sub>E</sub>-V<sub>F</sub> (focal servo ON, radial servo OFF)

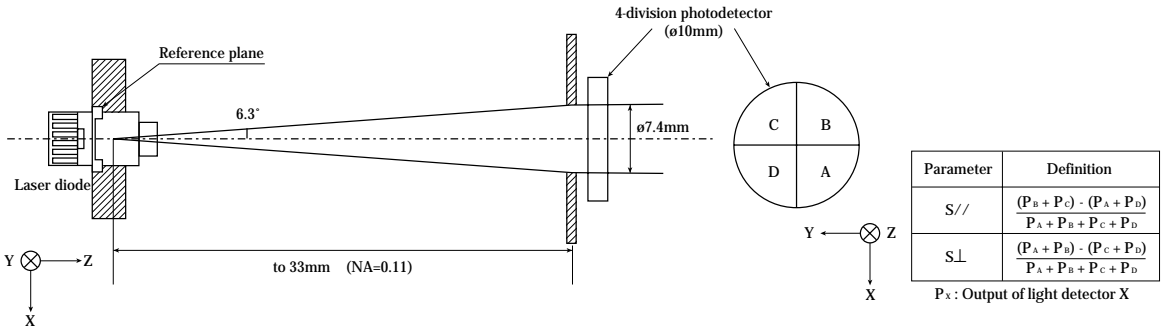


■ Electro-optical Characteristics of Laser Diode (Design Standard\*)

(T<sub>C</sub>=25°C)

Parameter			Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Emission characteristics	※1 Symmetry	Parallel	S//	Po=3mW, Into NA=0.11	-25	-	+25	%
		Perpendicular	S⊥		-15	-	+15	%
Misalignment position			Δx	—	-80	-	+80	μm
			Δy		-80	-	+80	μm
			Δz		-80	-	+80	μm
Interference pattern intensity			α	Po=3mW	-	-	0.97	-

※1 Measuring method of radiation symmetry



■ Electrical Characteristics of Monitor Photodiode (Design Standard\*)

(T<sub>C</sub>=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
※2 Sensitivity	S	V <sub>R</sub> =15V	-	0.20	-	mA/mW
Dark current	I <sub>D</sub>		-	-	150	nA
Terminal capacitance	C <sub>t</sub>		-	3.5	-	pF

※2 For hologram output power

■ Electro-optical Characteristics of OPIC for Signal Detection (Design Standard\*)

(T<sub>C</sub>=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit	※3 Segment
Supply voltage	V <sub>CC</sub>		3.0	-	5.5	V	
Supply current	I <sub>CC</sub>	V <sub>CC</sub> =5V	2	5	10	mA	
※4 Output offset voltage	V <sub>OD</sub>	V <sub>CC</sub> =5V No light	-25	0	+25	mV	V <sub>A-F</sub>
Offset voltage difference	ΔV <sub>OD</sub>		-15	0	+15	mV	V <sub>A</sub> -V <sub>B</sub> , V <sub>E</sub> -V <sub>F</sub>
Response frequency	f <sub>CF</sub>	※5 V <sub>CC</sub> =5V, -3dB R <sub>L</sub> =10kΩ	3	5	-	MHz	V <sub>A</sub> , V <sub>B</sub> , V <sub>C</sub>
	f <sub>CR</sub>		0.5	1	-	MHz	V <sub>E</sub> , V <sub>F</sub>

※3 Applicable divisions correspond to output terminals.

※4 Difference from V<sub>CC</sub>/2

※5 Output amplitude=0dB (input signal 100kHz) BW=10kHz

Segment No.		Output
D1	D4	D 1 .....V <sub>E</sub>
D2		D 2 .....V <sub>A</sub>
D3		D 3 .....V <sub>B</sub>
D4		D 4 .....V <sub>C</sub>
D5		D 5 .....V <sub>F</sub>

\* These parameters are not guaranteed performance, but general specifications of each optical element which makes up a hologram laser.  
• Please refer to the chapter "Handling Precautions"

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